National Semiconductor

March 1993

54AC/74AC377 • 54ACT/74ACT377
Octal D Flip-Flop with Clock Enable

General Description

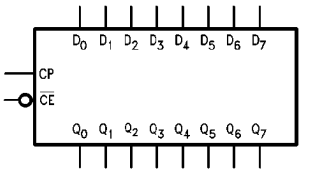
The 'AC/'ACT377 has eight edge-triggered, D-type flip-flops with individual D inputs and Q outputs. The common buffered Clock (CP) input loads all flip-flops simultaneously, when the Clock Enable ($\overline{CE}$) is LOW.

The register is fully edge-triggered. The state of each D input, one setup time before the LOW-to-HIGH clock transition, is transferred to the corresponding flip-flop's Q output. The $\overline{CE}$ input must be stable only one setup time prior to the LOW-to-HIGH clock transition for predictable operation.

Features

- I_{CC} reduced by 50%
- Ideal for addressable register applications
- Clock enable for address and data synchronization applications
- Eight edge-triggered D flip-flops
- Buffered common clock
- Outputs source/sink 24 mA
- See '273 for master reset version
- See '373 for transparent latch version
- See '374 for TRI-STATE® version
- 'ACT377 has TTL-compatible inputs
- Standard Military Drawing (SMD)
  - — 'AC377: 5962-88702
  - — 'ACT377: 5962-87697

Logic Symbols



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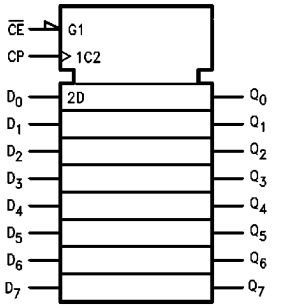
IEEE/IEC



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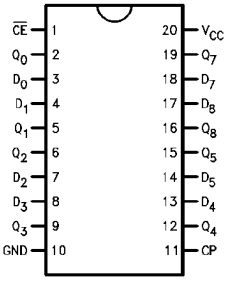
Pin Names	Description
D_0–D_7	Data Inputs
$\overline{CE}$	Clock Enable (Active LOW)
Q_0–Q_7	Data Outputs
CP	Clock Pulse Input

Connection Diagrams

Pin Assignment for DIP, Flatpak and SOIC



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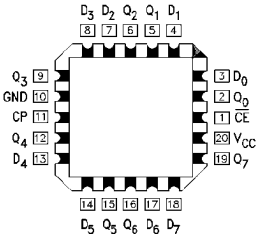
Pin Assignment for LCC



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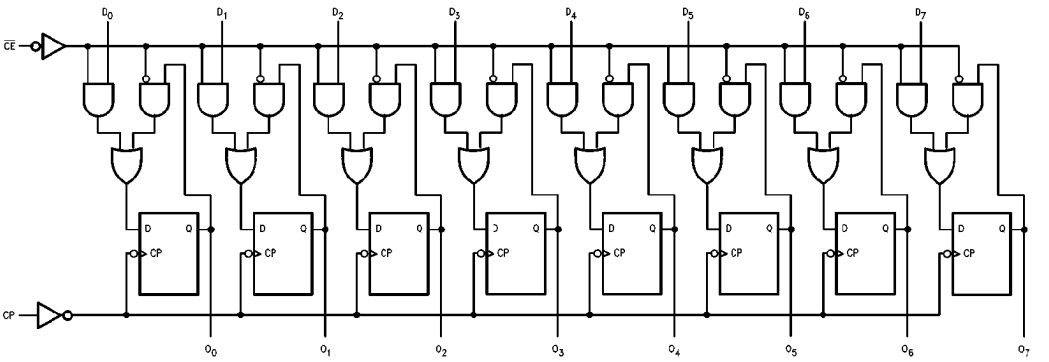
RRD-B30M75/Printed in U. S. A.

Mode Select-Function Table

Operating Mode	Inputs			Outputs
	CP	$\overline{CE}$	D_n	Q_n
Load '1'	⌐	L	H	H
Load '0'	⌐	L	L	L
Hold (Do Nothing)	⌐	H	X	No Change
	X	H	X	No Change

H = HIGH Voltage Level
L = LOW Voltage Level
X = Immaterial
⌐ = LOW-to-HIGH Clock Transition

Logic Diagram



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Please note that this diagram is provided only for the understanding of logic operations and should not be used to estimate propagation delays.

Absolute Maximum Rating (Note 1)

If Military/Aerospace specified devices are required, please contact the National Semiconductor Sales Office/Distributors for availability and specifications.

Supply Voltage (V_{CC})	−0.5V to +7.0V
DC Input Diode Current (I_{IK})	
V_I = −0.5V	−20 mA
V_I = V_{CC} + 0.5V	+20 mA
DC Input Voltage (V_I)	−0.5V to V_{CC} + 0.5V
DC Output Diode Current (I_{OK})	
V_O = −0.5V	−20 mA
V_O = V_{CC} + 0.5V	+20 mA
DC Output Voltage (V_O)	−0.5V to V_{CC} + 0.5V
DC Output Source or Sink Current (I_O)	±50 mA
DC V_{CC} or Ground Current per Output Pin (I_{CC} or I_{GND})	±50 mA
Storage Temperature (T_{STG})	−65°C to +150°C
Junction Temperature (T_J)	
CDIP	175°C
PDIP	140°C

Note 1: Absolute maximum ratings are those values beyond which damage to the device may occur. The databook specifications should be met, without exception, to ensure that the system design is reliable over its power supply, temperature, and output/input loading variables. National does not recommend operation of FACT™ circuits outside databook specifications.

Recommended Operating Conditions

Supply Voltage (V_{CC})	
'AC	2.0V to 6.0V
'ACT	4.5V to 5.5V
Input Voltage (V_I)	0V to V_{CC}
Output Voltage (V_O)	0V to V_{CC}
Operating Temperature (T_A)	
74AC/ACT	−40°C to +85°C
54AC/ACT	−55°C to +125°C
Minimum Input Edge Rate (ΔV/Δt) 'AC Devices V_{IN} from 30% to 70% of V_{CC} V_{CC} @ 3.3V, 4.5V, 5.5V	125 mV/ns
Minimum Input Edge Rate (ΔV/Δt) 'ACT Devices V_{IN} from 0.8V to 2.0V V_{CC} @ 4.5V, 5.5V	125 mV/ns

Note 2: See individual datasheets for those devices which differ from the typical input rise and fall times noted here.

DC Characteristics for 'AC Family Devices

Symbol	Parameter	V_{CC} (V)	74AC T_A = +25°C		54AC T_A = −55°C to +125°C	74AC T_A = −40°C to +85°C	Units	Conditions
			Typ	Guaranteed Limits				
V_{IH}	Minimum High Level Input Voltage	3.0	1.5	2.1	2.1	2.1	V	V_{OUT} = 0.1V or V_{CC} − 0.1V
		4.5	2.25	3.15	3.15	3.15		
		5.5	2.75	3.85	3.85	3.85		
V_{IL}	Maximum Low Level Input Voltage	3.0	1.5	0.9	0.9	0.9	V	V_{OUT} = 0.1V or V_{CC} − 0.1V
		4.5	2.25	1.35	1.35	1.35		
		5.5	2.75	1.65	1.65	1.65		
V_{OH}	Minimum High Level Output Voltage	3.0	2.99	2.9	2.9	2.9	V	I_{OUT} = −50 μA
		4.5	4.49	4.4	4.4	4.4		
		5.5	5.49	5.4	5.4	5.4		
		3.0		2.56	2.4	2.46	V	*V_{IN} = V_{IL} or V_{IH} I_{OH} −12 mA
		4.5		3.86	3.7	3.76		I_{OH} −24 mA
		5.5		4.86	4.7	4.76		−24 mA
V_{OL}	Maximum Low Level Output Voltage	3.0	0.002	0.1	0.1	0.1	V	I_{OUT} = 50 μA
		4.5	0.001	0.1	0.1	0.1		
		5.5	0.001	0.1	0.1	0.1		
		3.0		0.36	0.50	0.44	V	*V_{IN} = V_{IL} or V_{IH} I_{OL} 12 mA
		4.5		0.36	0.50	0.44		I_{OL} 24 mA
		5.5		0.36	0.50	0.44		24 mA
I_{IN}	Maximum Input Leakage Current	5.5		±0.1	±1.0	±1.0	μA	V_I = V_{CC}, GND

*All outputs loaded; thresholds on input associated with output under test.

DC Characteristics for 'AC Family Devices (Continued)

Symbol	Parameter	V_{CC} (V)	74AC T_A = +25°C		54AC T_A = −55°C to +125°C	74AC T_A = −40°C to +85°C	Units	Conditions
			Typ	Guaranteed Limits				
I_{OLD}	†Minimum Dynamic Output Current	5.5			50	75	mA	V_{OLD} = 1.65V Max
I_{OHD}		5.5			−50	−75	mA	V_{OHD} = 3.85V Min
I_{CC}	Maximum Quiescent Supply Current	5.5		4.0	80.0	40.0	μA	V_{IN} = V_{CC} or GND

†Maximum test duration 2.0 ms, one output loaded at a time.

Note: I_{IN} and I_{CC} @ 3.0V are guaranteed to be less than or equal to the respective limit @ 5.5V V_{CC}.
I_{CC} for 54AC @ 25°C is identical to 74AC @ 25°C.

DC Characteristics for 'ACT Family Devices

Symbol	Parameter	V_{CC} (V)	74ACT T_A = +25°C		54ACT T_A = −55°C to +125°C	74ACT T_A = −40°C to +85°C	Units	Conditions
			Typ	Guaranteed Limits				
V_{IH}	Minimum High Level Input Voltage	4.5 5.5	1.5 1.5	2.0 2.0	2.0 2.0	2.0 2.0	V	V_{OUT} = 0.1V or V_{CC} − 0.1V
V_{IL}	Maximum Low Level Input Voltage	4.5 5.5	1.5 1.5	0.8 0.8	0.8 0.8	0.8 0.8	V	V_{OUT} = 0.1V or V_{CC} − 0.1V
V_{OH}	Minimum High Level Output Voltage	4.5 5.5	4.49 5.49	4.4 5.4	4.4 5.4	4.4 5.4	V	I_{OUT} = −50 μA
		4.5 5.5		3.86 4.86	3.70 4.70	3.76 4.76	V	*V_{IN} = V_{IL} or V_{IH} I_{OH} −24 mA I_{OH} −24 mA
V_{OL}	Maximum Low Level Output Voltage	4.5 5.5	0.001 0.001	0.1 0.1	0.1 0.1	0.1 0.1	V	I_{OUT} = 50 μA
		4.5 5.5		0.36 0.36	0.50 0.50	0.44 0.44	V	*V_{IN} = V_{IL} or V_{IH} I_{OL} 24 mA I_{OL} 24 mA
I_{IN}	Maximum Input Leakage Current	5.5		±0.1	±1.0	±1.0	μA	V_I = V_{CC}, GND
I_{CCT}	Maximum I_{CC}/Input	5.5	0.6		1.6	1.5	mA	V_I = V_{CC} − 2.1V
I_{OLD}	†Minimum Dynamic Output Current	5.5			50	75	mA	V_{OLD} = 1.65V Max
I_{OHD}		5.5			−50	−75	mA	V_{OHD} = 3.85V Min
I_{CC}	Maximum Quiescent Supply Current	5.5		4.0	80.0	40.0	μA	V_{IN} = V_{CC} or GND

*All outputs loaded; thresholds on input associated with output under test.

†Maximum test duration 2.0 ms, one output loaded at a time.

Note: I_{CC} for 54ACT @ 25°C is identical to 74ACT @ 25°C.

AC Electrical Characteristics

Symbol	Parameter	V_{CC}* (V)	74AC $T_A = +25°C$, $C_L = 50$ pF			54AC $T_A = -55°C$ to $+125°C$, $C_L = 50$ pF		74AC $T_A = -40°C$ to $+85°C$, $C_L = 50$ pF		Units
			Min	Typ	Max	Min	Max	Min	Max	
f_{max}	Maximum Clock Frequency	3.3 5.0	90 140	125 175		75 95		75 125		MHz
t_{PLH}	Propagation Delay CP to Q_n	3.3 5.0	3.0 2.0	8.0 6.0	13.0 9.0	1.0 1.5	14.0 10.0	1.5 1.5	14.0 10.0	ns
t_{PHL}	Propagation Delay CP to Q_n	3.3 5.0	3.5 2.5	8.5 6.5	13.0 10.0	1.0 1.5	15.0 11.0	2.0 1.5	14.5 11.0	ns

*Voltage Range 3.3 is 3.3V ±0.3V
Voltage Range 5.0 is 5.0V ±0.5V

AC Operating Requirements

Symbol	Parameter	V_{CC}* (V)	74AC $T_A = +25°C$, $C_L = 50$ pF		54AC $T_A = -55°C$ to $+125°C$, $C_L = 50$ pF	74AC $T_A = -40°C$ to $+85°C$, $C_L = 50$ pF	Units
			Typ	Guaranteed Minimum			
t_s	Setup Time, HIGH or LOW D_n to CP	3.3 5.0	3.5 2.5	5.5 4.0	7.5 6.0	6.0 4.5	ns
t_h	Hold Time, HIGH or LOW D_n to CP	3.3 5.0	−2.0 −1.0	0 1.0	1.5 2.5	0 1.0	ns
t_s	Setup Time, HIGH or LOW $\overline{CE}$ to CP	3.3 5.0	4.0 2.5	6.0 4.0	9.5 6.0	7.5 4.5	ns
t_h	Hold Time, HIGH or LOW $\overline{CE}$ to CP	3.3 5.0	−3.5 −2.0	0 1.0	1.0 2.0	0 1.0	ns
t_w	CP Pulse Width HIGH or LOW	3.3 5.0	3.5 2.5	5.5 4.0	6.5 5.0	6.0 4.5	ns

*Voltage Range 3.3 is 3.0V ±0.3V
Voltage Range 5.0 is 5.0V ±0.5V

AC Electrical Characteristics

Symbol	Parameter	V_{CC}* (V)	74ACT $T_A = +25°C$, $C_L = 50$ pF			54ACT $T_A = -55°C$ to $+125°C$, $C_L = 50$ pF		74ACT $T_A = -40°C$ to $+85°C$, $C_L = 50$ pF		Units
			Min	Typ	Max	Min	Max	Min	Max	
f_{max}	Maximum Clock Frequency	5.0	140	175		85		125		MHz
t_{PLH}	Propagation Delay CP to Q_n	5.0	3.0	6.5	9.0	1.5	11.0	2.5	10.0	ns
t_{PHL}	Propagation Delay CP to Q_n	5.0	3.5	7.0	10.0	1.5	12.0	2.5	11.0	ns

*Voltage Range 5.0 is 5.0V ±0.5V

AC Operating Requirements

Symbol	Parameter	V_{CC}* (V)	74ACT $T_A = +25°C$, $C_L = 50$ pF		54ACT $T_A = -55°C$ to $+125°C$, $C_L = 50$ pF	74ACT $T_A = -40°C$ to $+85°C$, $C_L = 50$ pF	Units
			Typ	Guaranteed Minimum			
t_s	Setup Time, HIGH or LOW D_n to CP	5.0	2.5	4.5	7.0	5.5	ns
t_h	Hold Time, HIGH or LOW D_n to CP	5.0	−1.0	1.0	1.0	1.0	ns
t_s	Setup Time, HIGH or LOW $\overline{CE}$ to CP	5.0	2.5	4.5	7.0	5.5	ns
t_h	Hold Time, HIGH or LOW $\overline{CE}$ to CP	5.0	−1.0	1.0	1.0	1.0	ns
t_w	CP Pulse Width HIGH or LOW	5.0	2.0	4.0	5.5	4.5	ns

*Voltage Range 5.0 is 5.0V ±0.5V

Capacitance

Symbol	Parameter	Typ	Units	Conditions
C_{IN}	Input Capacitance	4.5	pF	V_{CC} = OPEN
C_{PD}	Power Dissipation Capacitance	90.0	pF	V_{CC} = 5.0V

Ordering Information

The device number is used to form part of a simplified purchasing code where the package type and temperature range are defined as follows:

74ACT 377 P C QR

Temperature Range Family
- 74AC = Commercial
- 54AC = Military
- 74ACT = Commercial TTL-Compatible
- 54ACT = Military TTL-Compatible

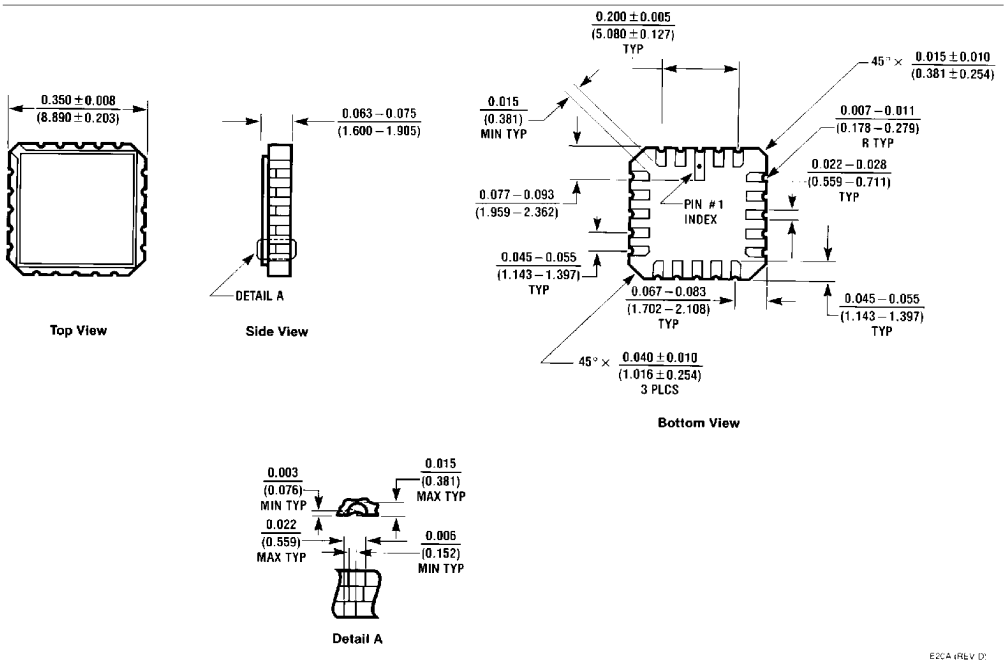
Device Type

Package Code
- P = Plastic DIP
- D = Ceramic DIP
- F = Flatpak
- L = Leadless Ceramic Chip Carrier (LCC)
- S = Small Outline (SOIC)

Temperature Range
- C = Commercial (−40°C to +85°C)
- M = Military (−55°C to +125°C)

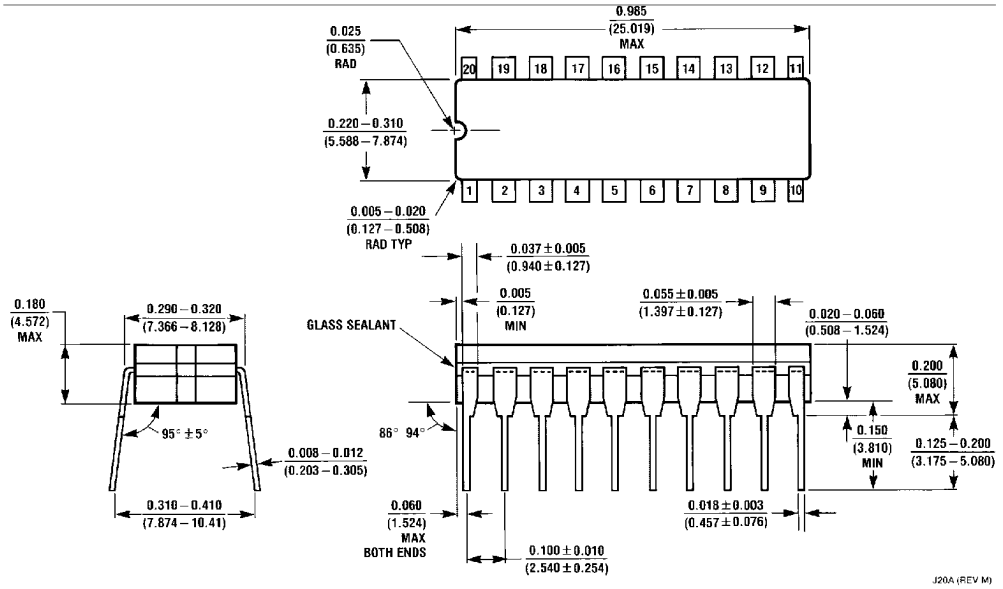
Special Variations
- X = Devices shipped in 13″ reels
- QR = Commercial grade device with burn-in
- QB = Military grade device with environmental and burn-in processing shipped in tubes

Physical Dimensions inches (millimeters)

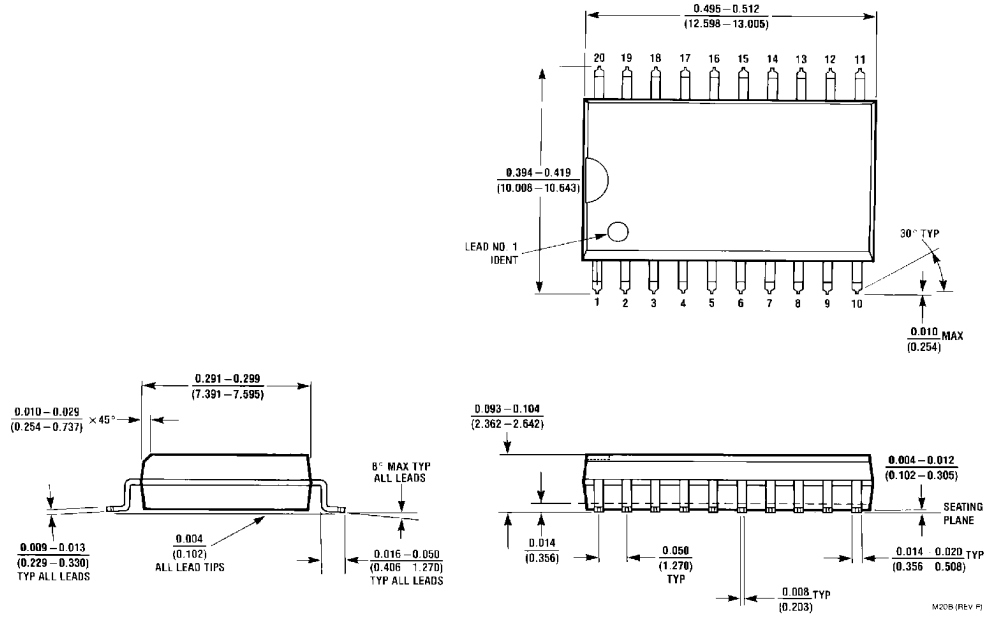


20 Terminal Ceramic Leadless Chip Carrier (L)
NS Package Number E20A

Physical Dimensions inches (millimeters) (Continued)

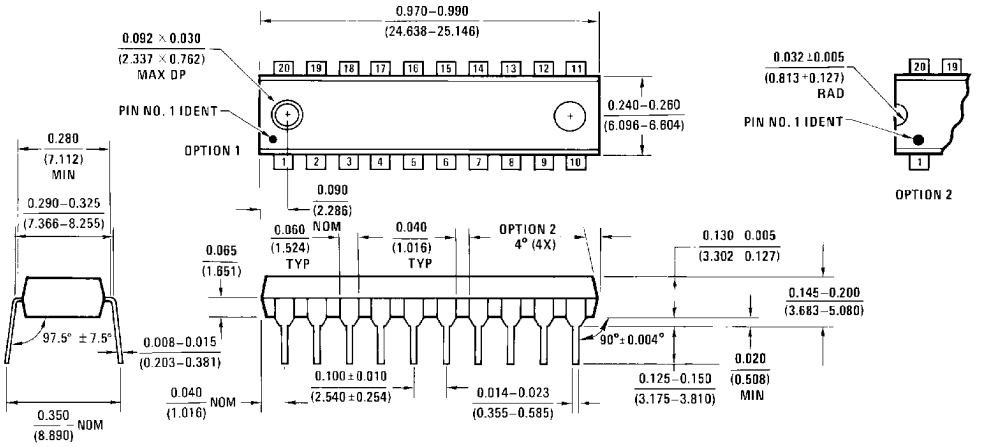


20 Lead Ceramic Dual-In-Line Package (D)
NS Package Number J20A



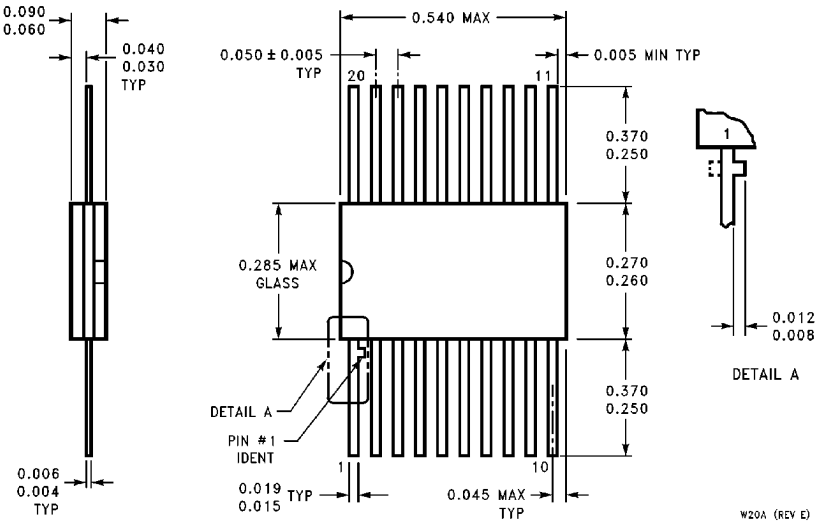
20 Lead Small Outline Integrated Circuit (S)
NS Package Number M20B

Physical Dimensions inches (millimeters) (Continued)



20 Lead Plastic Dual-In-Line Package (P)
NS Package Number N20B

Physical Dimensions inches (millimeters) (Continued)



20 Lead Ceramic Flatpak (F)
NS Package Number W20A

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2. A critical component is any component of a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or system, or to affect its safety or effectiveness.

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